NSN 5961-01-328-9025

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View Online at https://aerobasegroup.com/nsn/5961-01-328-9025 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **End Application:** F/a-18 hornet **Mounting Facility Quantity: Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 3.40 amperes drain current and 10.00 amperes peak pulse current **Power Rating Per Characteristic:** 78.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Weapon system essential **Test Data Document:** 09344-pc71637 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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